

Supplementary Information

Strain and Electric Field Modulated Electronic Structure of Two-dimensional SiP(SiAs)/GeS van der Waals Heterostructures

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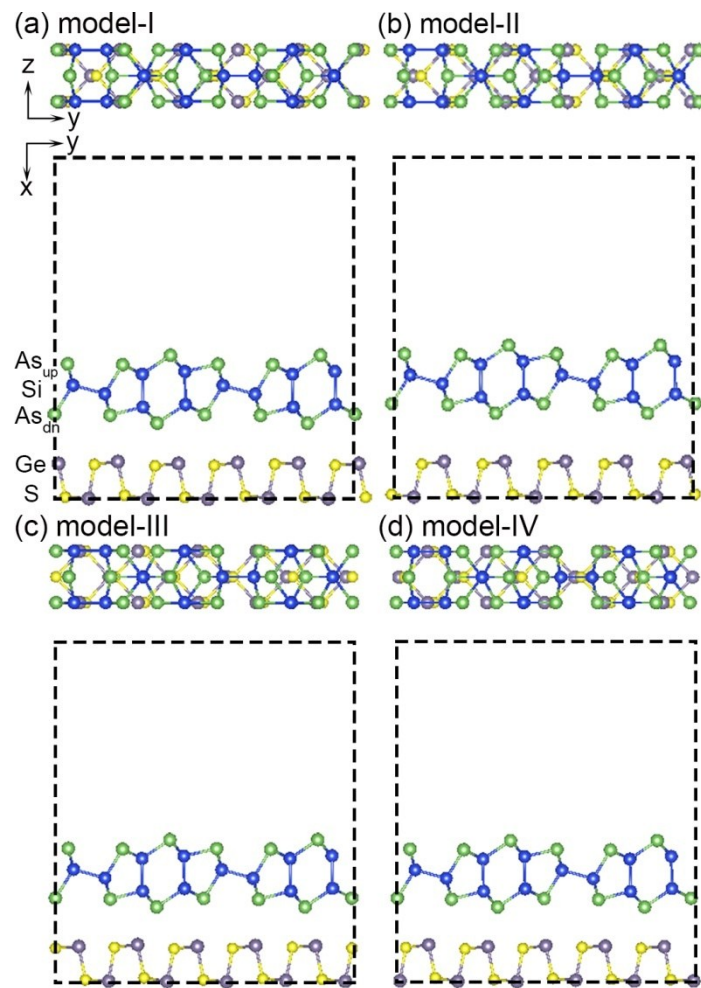


Fig. S1. Top and side views of (a) model-I, (b) model-II, (c) model-III and (d) model-IV for SiAs/GeS heterostructures.